

# PQMB11

PNP/PNP resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 26 October 2015

**Product data sheet** 

# 1. General description

PNP/PNP Resistor-Equipped Transistors (RET) in a leadless ultra small DFN1010B-6 (SOT1216) Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: PQMH11.

NPN/PNP complement: PQMD3.

## 2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Low package height of 0.37 mm
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

### 3. Applications

- Low current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications
- Mobile applications

# 4. Quick reference data

Table 1. Qu	ick reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transisto	r						
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	-50	V
Ι <sub>Ο</sub>	output current			-	-	-100	mA
Per transisto	r		I				
R1	bias resistor 1	T <sub>amb</sub> = 25 °C	[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	

[1] See section "Test information" for resistor calculation and test conditions.





# 5. Pinning information

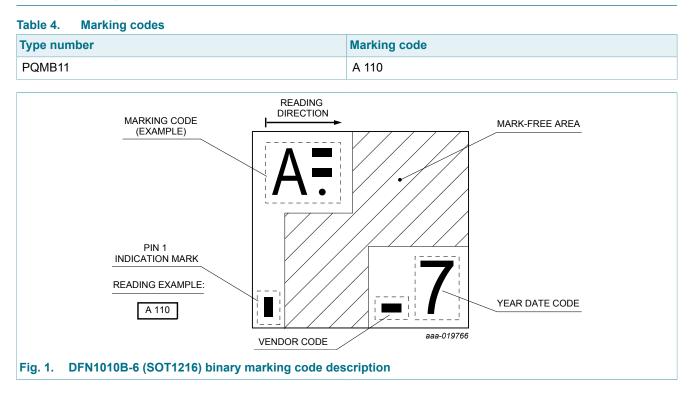
Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		01 I2 GND2
2	11	input ( base) TR1		
3	02	output (collector) TR2		
4	GND2	GND (emitter) TR2		
5	12	input ( base) TR2	3 4	
6	01	output (collector) TR1	Transparent top view	
7	01	output (collector) TR1	DFN1010B-6 (SOT1216)	GND1 I1 02 aaa-019790
8	02	output (collector) TR2		

# 6. Ordering information

Table 3. Ordering information							
Type number	Package	ackage					
	Name	Description	Version				
PQMB11	DFN1010B-6	DFN1010B-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1216				

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### 7. Marking



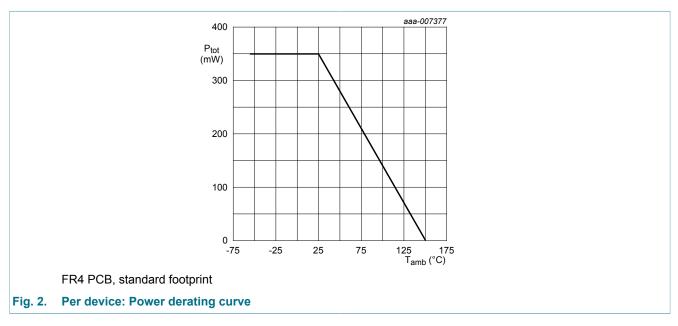
# 8. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transis	tor					
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-50	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-10	V
VI	input voltage	positive		-	10	V
		negative		-	-40	V
I <sub>O</sub>	output current			-	-100	mA
I <sub>CM</sub>	peak collector current			-	-100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	230	mW
Per device				-	- 1	
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	350	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

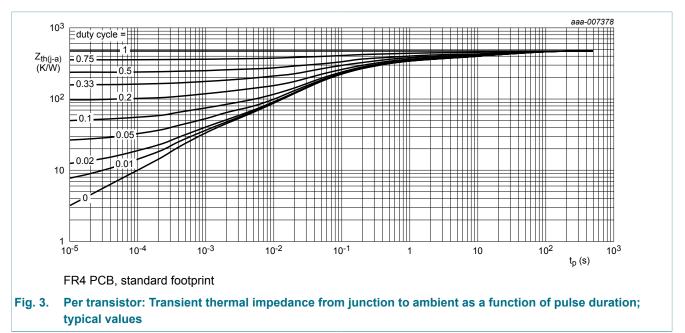


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### 9. Thermal characteristics

Table 6. The	rmal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	543	K/W
Per device			Ì				
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	357	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



# **10. Characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transis	tor	1					
I <sub>CBO</sub>	collector-base cut-off current (emitter open)	$V_{CB}$ = -50 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-100	nA
I <sub>CEO</sub>	collector-emitter cut-off	$V_{CE}$ = -30 V; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-1	μA
	current (base open)	$V_{CE}$ = -30 V; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 150 °C		-	-	-5	μA
I <sub>EBO</sub>	emitter-base cut-off current (collector open)	$V_{EB}$ = -5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-400	μA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -5 V; I <sub>C</sub> = -5 mA; T <sub>amb</sub> = 25 °C		30	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{C}$ = -10 mA; $I_{B}$ = -0.5 mA; $T_{amb}$ = 25 °C		-	-	-150	mV
V <sub>I(off)</sub>	off-state input voltage	$V_{CE}$ = -5 V; I <sub>C</sub> = -100 µA; T <sub>amb</sub> = 25 °C		-	-1.1	-0.8	V
V <sub>I(on)</sub>	on-state input voltage	$V_{CE}$ = -0.3 V; I <sub>C</sub> = -10 mA; T <sub>amb</sub> = 25 °C		-2.5	-1.8	-	V
R1	bias resistor 1	T <sub>amb</sub> = 25 °C	[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	
C <sub>C</sub>	collector capacitance	$V_{CB}$ = -10 V; I <sub>E</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C		-	-	3	pF
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -10 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C	[2]	-	180	-	MHz

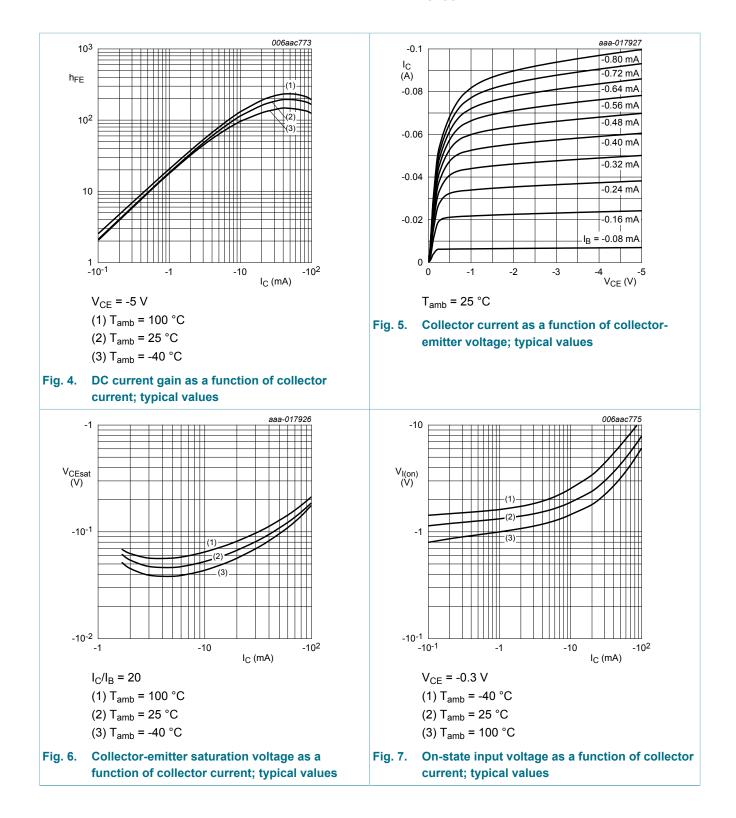
[1] See section "Test information" for resistor calculation and test conditions.

[2] Characteristics of built-in transistor

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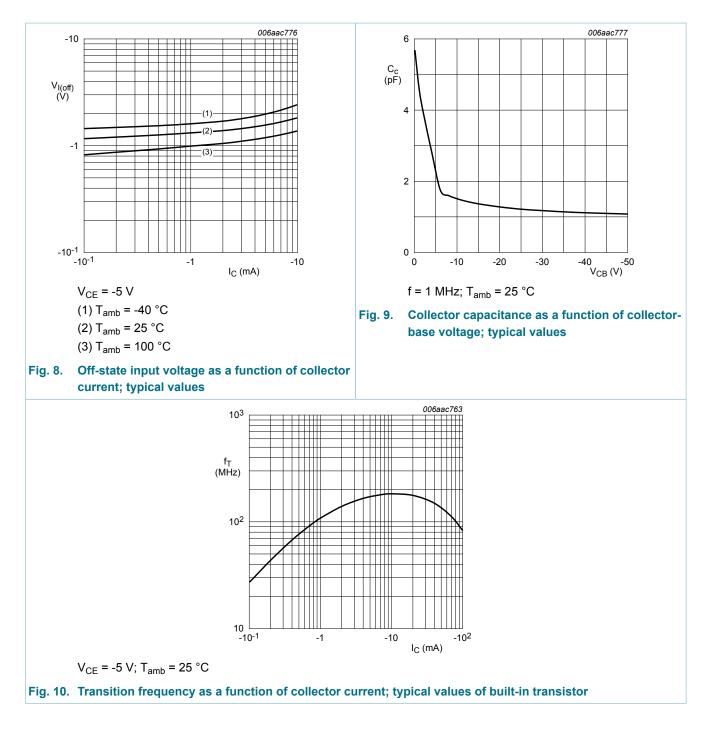
#### PNP/PNP resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$



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# **11. Test information**

#### **11.1 Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

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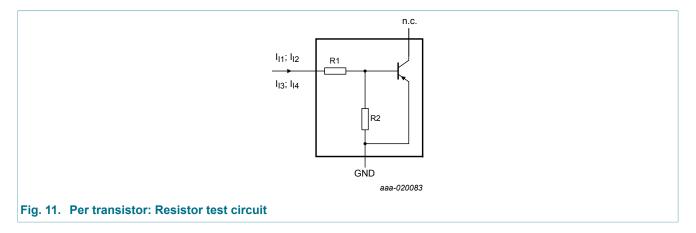
#### 11.2 Resistor calculation

• Calculation of bias resistor 1 (R1)

$$R1 = \frac{V(I_{12}) - V(I_{11})}{I_{12} - I_{11}}$$

• Calculation of bias resistor ratio (R2/R1)

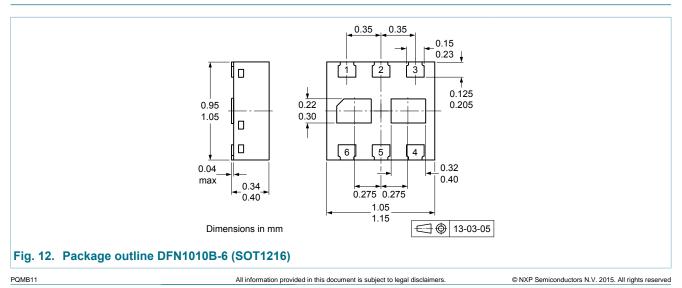
$$\frac{R2}{R1} = \frac{V(I_{14}) - V(I_{13})}{R1 \cdot (I_{14} - I_{13})} - 1$$



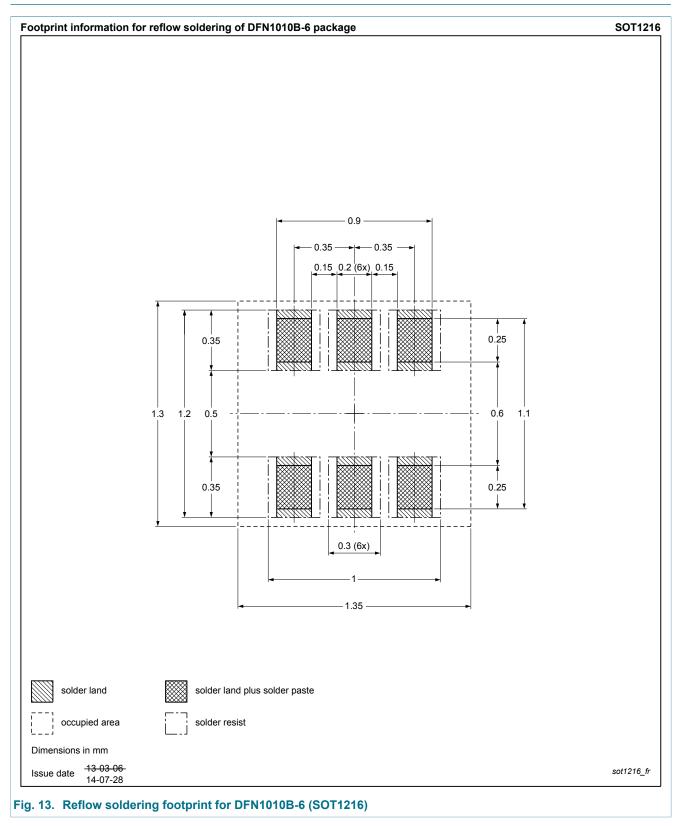
### 11.3 Resistor test conditions

Table 8.	<b>Resistor test conditions</b>				
R1 (kΩ)	R2 (kΩ)	Test conditions			
		I <sub>I1</sub>	I <sub>12</sub>	I <sub>I3</sub>	I <sub>14</sub>
10	10	-350 µA	-450 μA	350 µA	450 μΑ

# 12. Package outline



# **13. Soldering**



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# 14. Revision history

Table 9. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PQMB11 v.1	20151026	Product data sheet	-	-			

### **15. Legal information**

#### 15.1 Data sheet status

Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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